LM2832 High Frequency 2.0A Load - Step-Down DC-DC Regulator

Check for Samples: **LM2832**

FEATURES

- **Input Voltage Range of 3.0V to 5.5V**
- **Output Voltage Range of 0.6V to 4.5V**
- **2.0A Output Current**
- **High Switching Frequencies**
  - **1.6MHz (LM2832X)**
  - **0.55MHz (LM2832Y)**
  - **3.0MHz (LM2832Z)**
- **150mΩ PMOS Switch**
- **0.6V, 2% Internal Voltage Reference**
- **Internal Soft-Start**
- **Current Mode, PWM Operation**
- **Thermal Shutdown**
- **Over Voltage Protection**

APPLICATIONS

- **Local 5V to Vcore Step-Down Converters**
- **Core Power in HDDs**
- **Set-Top Boxes**
- **USB Powered Devices**
- **DSL Modems**

DESCRIPTION

The LM2832 regulator is a monolithic, high frequency, PWM step-down DC/DC converter in a 6 Pin WSON and a 8 Pin eMSOP-PowerPAD package. It provides all the active functions to provide local DC/DC conversion with fast transient response and accurate regulation in the smallest possible PCB area. With a minimum of external components, the LM2832 is easy to use. The ability to drive 2.0A loads with an internal 150 mΩ PMOS switch using state-of-the-art 0.5 µm BiCMOS technology results in the best power density available. The world-class control circuitry allows on-times as low as 30ns, thus supporting exceptionally high frequency conversion over the entire 3V to 5.5V input operating range down to the minimum output voltage of 0.6V. Switching frequency is internally set to 550 kHz, 1.6 MHz, or 3.0 MHz, allowing the use of extremely small surface mount inductors and chip capacitors. Even though the operating frequency is high, efficiencies up to 93% are easy to achieve. External shutdown is included, featuring an ultra-low stand-by current of 30 nA. The LM2832 utilizes current-mode control and internal compensation to provide high-performance regulation over a wide range of operating conditions. Additional features include internal soft-start circuitry to reduce inrush current, pulse-by-pulse current limit, thermal shutdown, and output over-voltage protection.

Typical Application Circuit
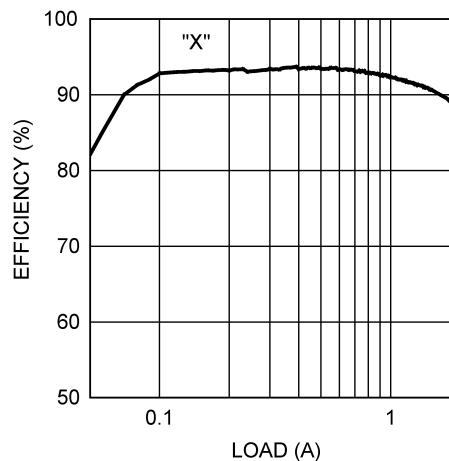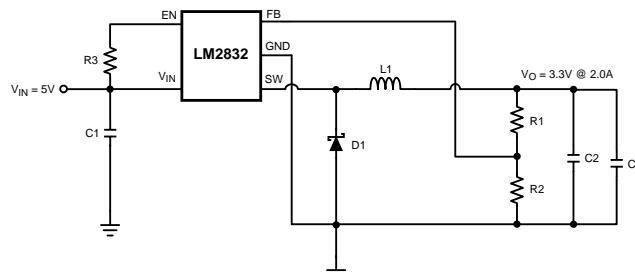
Connection Diagrams
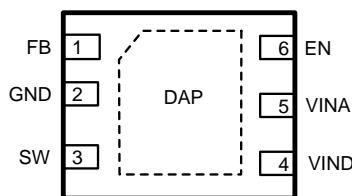
Figure 1. 6-Pin WSON
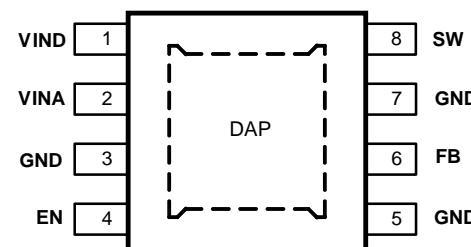
Figure 2. 8-Pin eMSOP-PowerPAD

PIN DESCRIPTIONS 8-PIN eMSOP-PowerPAD

Pin	Name	Function
1	VIND	Power Input supply.
2	VINA	Control circuitry supply voltage. Connect VINA to VIND on PC board.
3, 5, 7	GND	Signal and power ground pin. Place the bottom resistor of the feedback network as close as possible to this pin.
4	EN	Enable control input. Logic high enables operation. Do not allow this pin to float or be greater than VIN + 0.3V.
6	FB	Feedback pin. Connect to external resistor divider to set output voltage.
8	SW	Output switch. Connect to the inductor and catch diode.
DAP	Die Attach Pad	Connect to system ground for low thermal impedance, but it cannot be used as a primary GND connection.

PIN DESCRIPTIONS 6-PIN WSON

Pin	Name	Function
1	FB	Feedback pin. Connect to external resistor divider to set output voltage.
2	GND	Signal and power ground pin. Place the bottom resistor of the feedback network as close as possible to this pin.
3	SW	Output switch. Connect to the inductor and catch diode.
4	VIND	Power Input supply.
5	VINA	Control circuitry supply voltage. Connect VINA to VIND on PC board.
6	EN	Enable control input. Logic high enables operation. Do not allow this pin to float or be greater than VINA + 0.3V.
DAP	Die Attach Pad	Connect to system ground for low thermal impedance, but it cannot be used as a primary GND connection.

Absolute Maximum Ratings[1] [2]

VIN	-0.5V to 7V
FB Voltage	-0.5V to 3V
EN Voltage	-0.5V to 7V
SW Voltage	-0.5V to 7V
ESD Susceptibility	2kV
Junction Temperature[3]	150°C
Storage Temperature	−65°C to +150°C
Soldering Information	Infrared or Convection Reflow (15 sec)	220°C

(1)   Absolute maximum ratings indicate limits beyond which damage to the device may occur. Operating Range indicates conditions for which the device is intended to be functional, but does not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics.
(2)   If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
(3)   Thermal shutdown will occur if the junction temperature exceeds the maximum junction temperature of the device.

Operating Ratings

|	
VIN	3V to 5.5V
Junction Temperature	−40°C to +125°C

Electrical Characteristics

VIN = 5V unless otherwise indicated under the **Conditions** column. Limits in standard type are for T_J = 25°C only; limits in **boldface type** apply over the junction temperature (T_J) range of -40°C to +125°C. Minimum and Maximum limits are ensured through test, design, or statistical correlation. Typical values represent the most likely parametric norm at T_J = 25°C, and are provided for reference purposes only.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_{FB}	Feedback Voltage	WSON-6 Package	**0.588**	0.600	**0.612**	V
		eMSOP-PowerPAD-8 Package	**0.584**	0.600	**0.616**	
$\Delta V_{FB}/V_{IN}$	Feedback Voltage Line Regulation	V_{IN} = 3V to 5V		0.02		%/V
I_B	Feedback Input Bias Current			0.1	**100**	nA
UVLO	Undervoltage Lockout	V_{IN} Rising		2.73	**2.90**	V
		V_{IN} Falling	**1.85**	2.3		
	UVLO Hysteresis			0.43		V
F_{SW}	Switching Frequency	LM2832-X	**1.2**	1.6	**1.95**	MHz
		LM2832-Y	**0.4**	0.55	**0.7**	
		LM2832-Z	**2.25**	3.0	**3.75**	
D_{MAX}	Maximum Duty Cycle	LM2832-X	**86**	94		%
		LM2832-Y	**90**	96		
		LM2832-Z	**82**	90		
D_{MIN}	Minimum Duty Cycle	LM2832-X		5		%
		LM2832-Y		2		
		LM2832-Z		7		
$R_{DS(ON)}$	Switch On Resistance	WSON-6 Package		150		mΩ
		eMSOP-PowerPAD-8 Package		155	**240**	
I_{CL}	Switch Current Limit	V_{IN} = 3.3V	**2.4**	3.25		A
V_{EN_TH}	Shutdown Threshold Voltage				**0.4**	V
	Enable Threshold Voltage		**1.8**			
I_{SW}	Switch Leakage			100		nA
I_{EN}	Enable Pin Current	Sink/Source		100		nA
I_Q	Quiescent Current (switching)	LM2832X V_{FB} = 0.55		3.3	**5**	mA
		LM2831Y V_{FB} = 0.55		2.8	**4.5**	
		LM2832Z V_{FB} = 0.55		4.3	**6.5**	
	Quiescent Current (shutdown)	All Options V_{EN} = 0V		30		nA
θ_{JA}	Junction to Ambient 0 LFPM Air Flow[1]	WSON-6 and eMSOP-PowerPAD-8 Packages		80		°C/W
θ_{JC}	Junction to Case[1]	WSON-6 and eMSOP-PowerPAD-8 Packages		18		°C/W
T_{SD}	Thermal Shutdown Temperature			165		°C

(1) Applies for packages soldered directly onto a 3" x 3" PC board with 2oz. copper on 4 layers in still air.

Product Folder Links: *LM2832*

Typical Performance Characteristics

All curves taken at VIN = 5.0V with configuration in typical application circuit shown in Applications Information section of this datasheet. T_J = 25°C, unless otherwise specified.

η vs Load "X, Y and Z" Vin = 3.3V, Vo = 1.8V

Figure 3.

η vs Load "X" Vin = 5V, Vo = 1.8V & 3.3V

Figure 4.

η vs Load - "Y" Vin = 5V, Vo = 3.3V & 1.8V

Figure 5.

η vs Load "Z" Vin = 5V, Vo = 3.3V & 1.8V

Figure 6.

Load Regulation Vin = 3.3V, Vo = 1.8V (All Options)

Figure 7.

Load Regulation Vin = 5V, Vo = 1.8V (All Options)

Figure 8.

Product Folder Links: LM2832
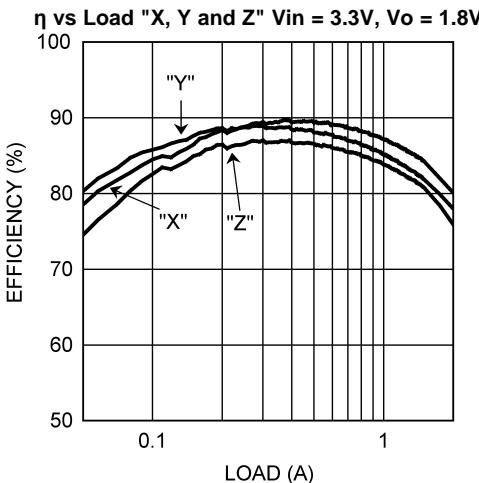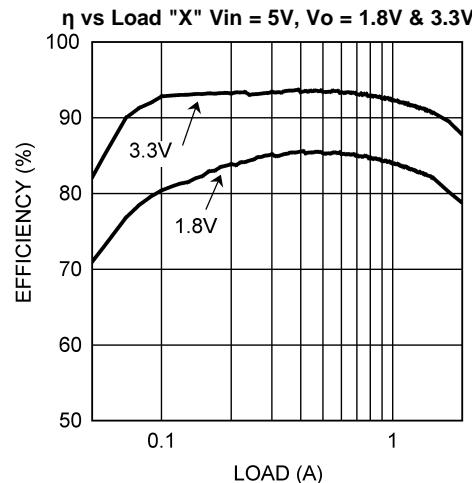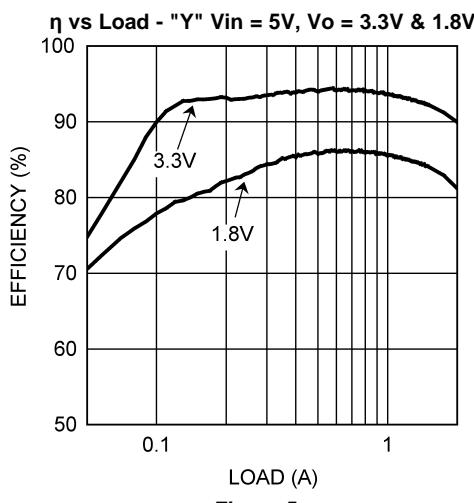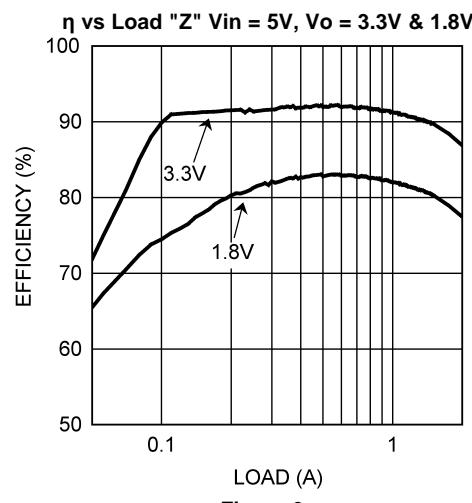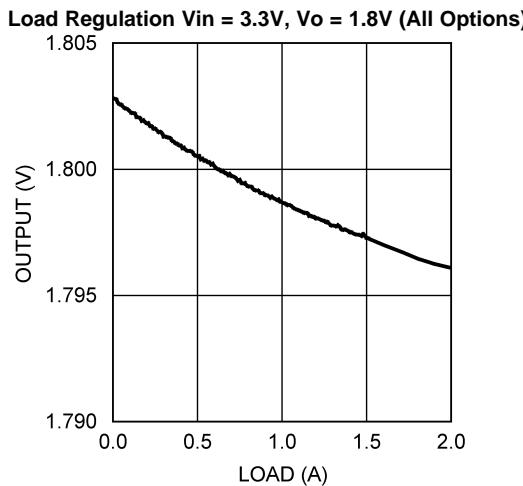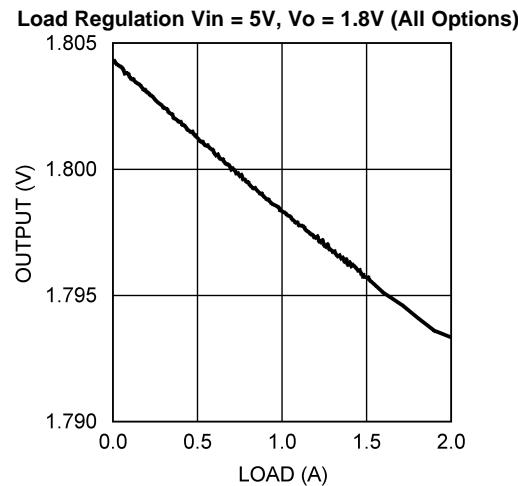
Typical Performance Characteristics (continued)

All curves taken at VIN = 5.0V with configuration in typical application circuit shown in Applications Information section of this datasheet. T_J = 25°C, unless otherwise specified.

**Load Regulation Vin = 5V, Vo = 3.3V (All Options)**
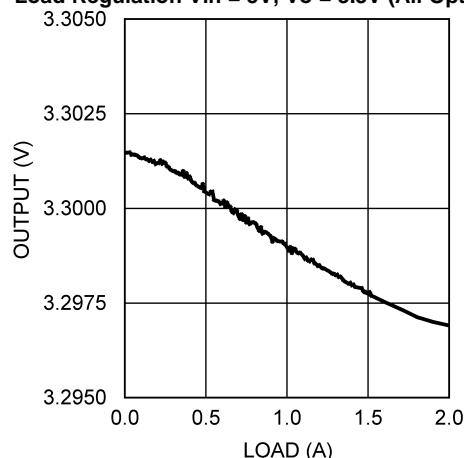
Figure 9.

**Oscillator Frequency vs Temperature - "X"**
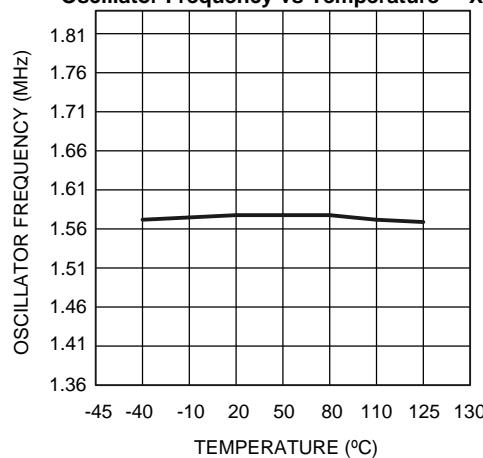
Figure 10.

**Oscillator Frequency vs Temperature - "Y"**
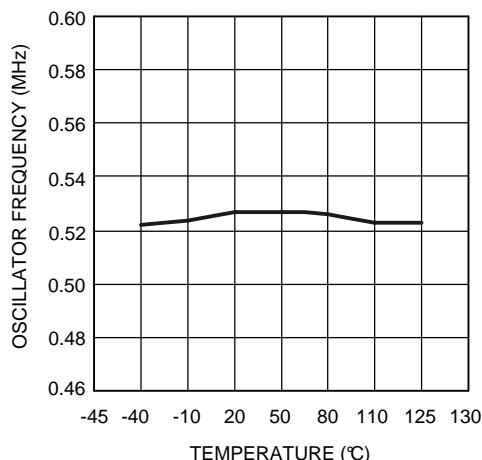
Figure 11.

Oscillator Frequency vs Temperature - "Z"
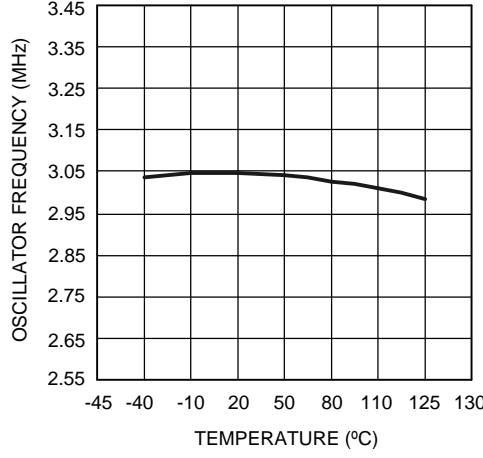
Figure 12.

Current Limit vs Temperature Vin = 3.3V
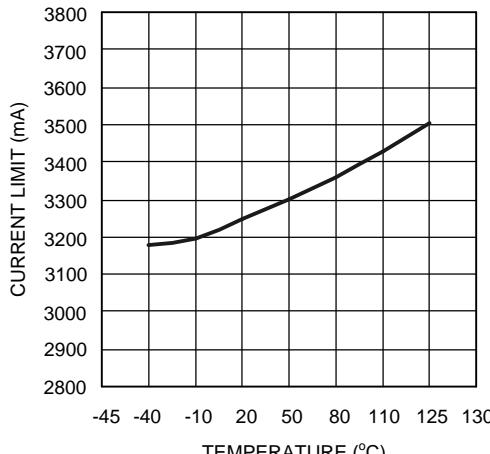
Figure 13.

RDSON vs Temperature (WSON-6 Package)
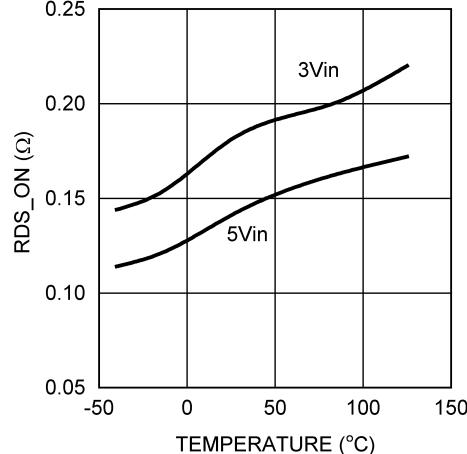
Figure 14.

Product Folder Links: *LM2832*

Typical Performance Characteristics (continued)

All curves taken at VIN = 5.0V with configuration in typical application circuit shown in Applications Information section of this datasheet. T_J = 25°C, unless otherwise specified.

RDSON vs Temperature (eMSOP-PowerPAD-8 Package)
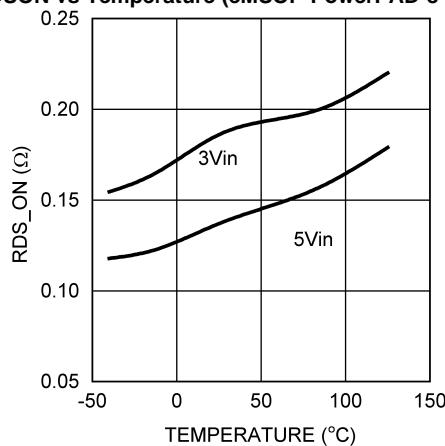
Figure 15.

LM2832X I_Q (Quiescent Current)
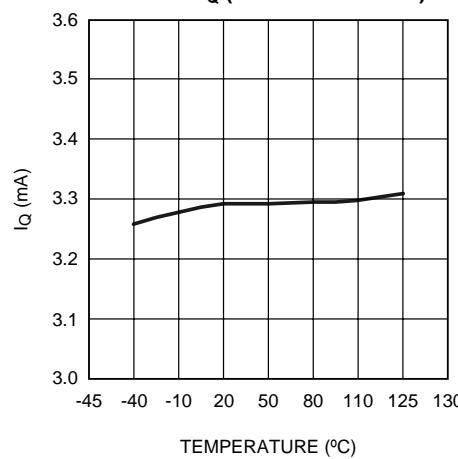
Figure 16.

LM2832Y I_Q (Quiescent Current)
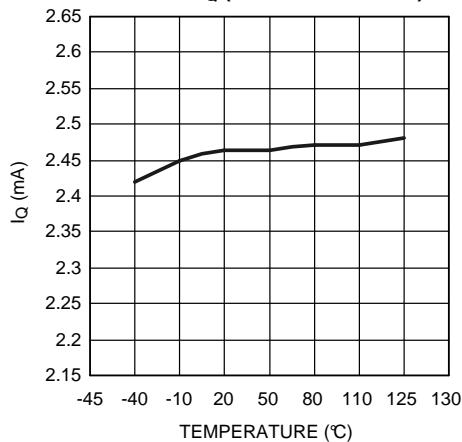
Figure 17.

LM2832Z I_Q (Quiescent Current)
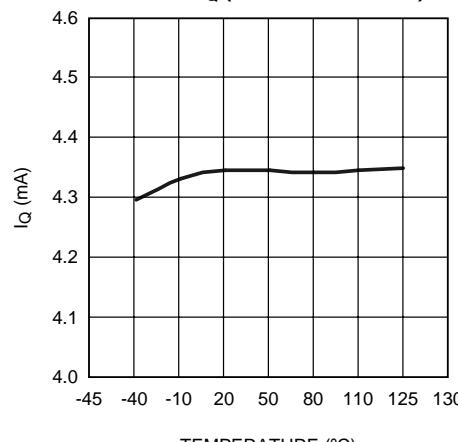
Figure 18.

Line Regulation Vo = 1.8V, Io = 500mA
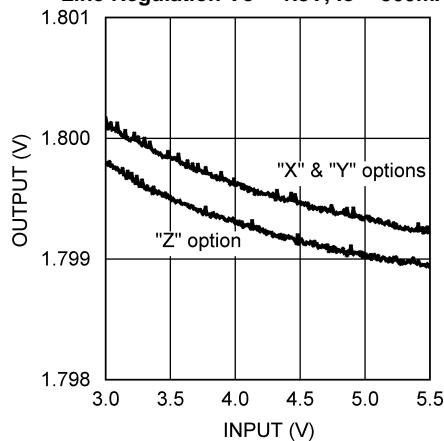
Figure 19.

V_{FB} vs Temperature
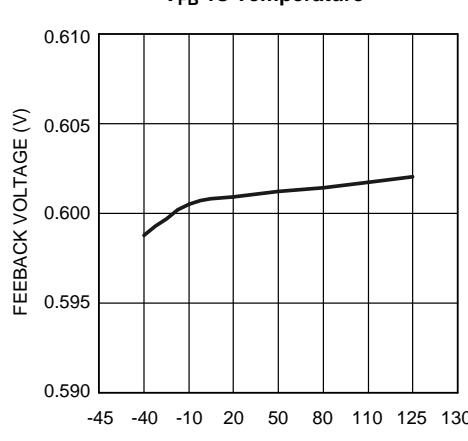
Figure 20.

Typical Performance Characteristics (continued)

All curves taken at VIN = 5.0V with configuration in typical application circuit shown in Applications Information section of this datasheet. T_J = 25°C, unless otherwise specified.

Gain vs Frequency (Vin = 5V, Vo = 1.2V @ 1A)
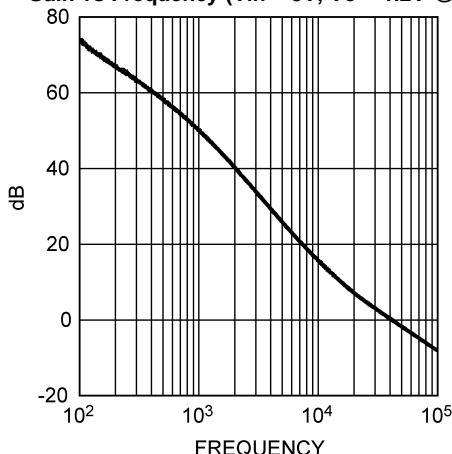
Phase Plot vs Frequency (Vin = 5V, Vo = 1.2V @ 1A)
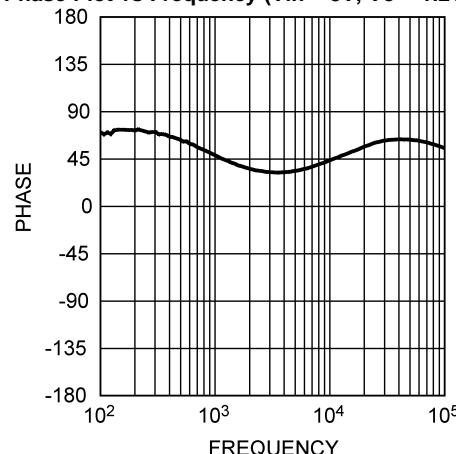
Figure 21.

Figure 22.

Simplified Block Diagram

Figure 23.

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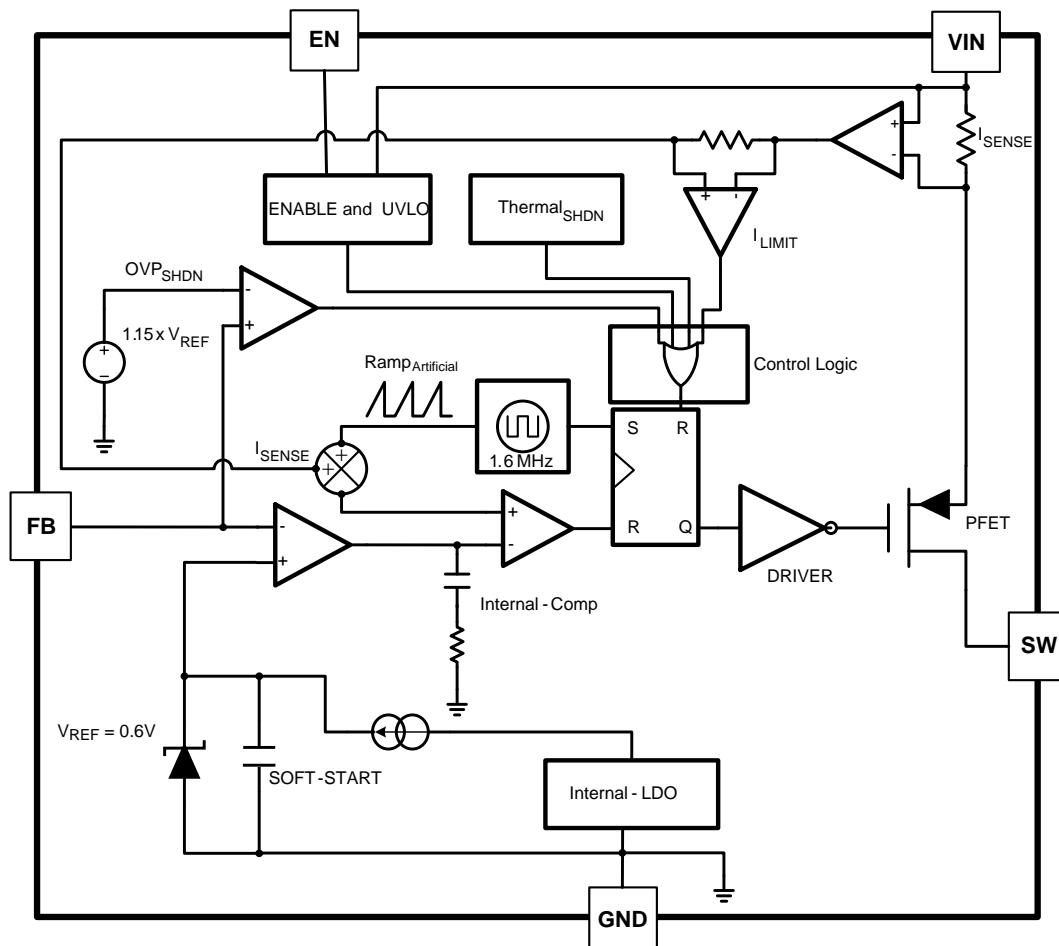
APPLICATIONS INFORMATION

THEORY OF OPERATION

The LM2832 is a constant frequency PWM buck regulator IC that delivers a 2.0A load current. The regulator has a preset switching frequency of 1.6MHz or 3.0MHz. This high frequency allows the LM2832 to operate with small surface mount capacitors and inductors, resulting in a DC/DC converter that requires a minimum amount of board space. The LM2832 is internally compensated, so it is simple to use and requires few external components. The LM2832 uses current-mode control to regulate the output voltage. The following operating description of the LM2832 will refer to the Simplified Block Diagram (Figure 23) and to the waveforms in Figure 24. The LM2832 supplies a regulated output voltage by switching the internal PMOS control switch at constant frequency and variable duty cycle. A switching cycle begins at the falling edge of the reset pulse generated by the internal oscillator. When this pulse goes low, the output control logic turns on the internal PMOS control switch. During this on-time, the SW pin voltage (V_{SW}) swings up to approximately V_{IN}, and the inductor current (I_L) increases with a linear slope. I_L is measured by the current sense amplifier, which generates an output proportional to the switch current. The sense signal is summed with the regulator's corrective ramp and compared to the error amplifier's output, which is proportional to the difference between the feedback voltage and V_{REF}. When the PWM comparator output goes high, the output switch turns off until the next switching cycle begins. During the switch off-time, inductor current discharges through the Schottky catch diode, which forces the SW pin to swing below ground by the forward voltage (V_D) of the Schottky catch diode. The regulator loop adjusts the duty cycle (D) to maintain a constant output voltage.
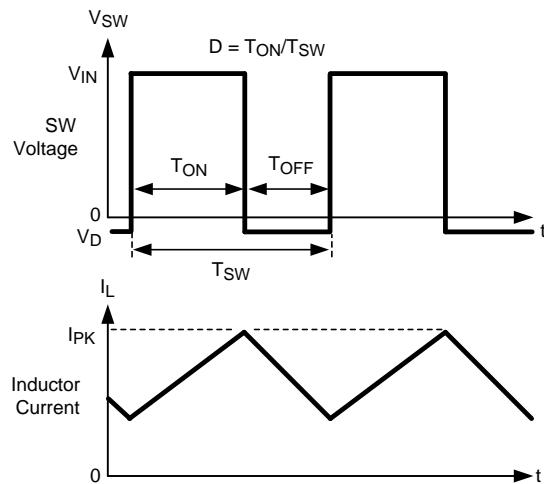
Figure 24. Typical Waveforms

SOFT-START

This function forces V_{OUT} to increase at a controlled rate during start up. During soft-start, the error amplifier's reference voltage ramps from 0V to its nominal value of 0.6V in approximately 600 µs. This forces the regulator output to ramp up in a controlled fashion, which helps reduce inrush current.

OUTPUT OVERVOLTAGE PROTECTION

The over-voltage comparator compares the FB pin voltage to a voltage that is 15% higher than the internal reference V_{REF}. Once the FB pin voltage goes 15% above the internal reference, the internal PMOS control switch is turned off, which allows the output voltage to decrease toward regulation.

UNDERVOLTAGE LOCKOUT

Under-voltage lockout (UVLO) prevents the LM2832 from operating until the input voltage exceeds 2.73V (typ). The UVLO threshold has approximately 430 mV of hysteresis, so the part will operate until V_{IN} drops below 2.3V (typ). Hysteresis prevents the part from turning off during power up if V_{IN} is non-monotonic.

Product Folder Links: *LM2832*

CURRENT LIMIT

The LM2832 uses cycle-by-cycle current limiting to protect the output switch. During each switching cycle, a current limit comparator detects if the output switch current exceeds 3.25A (typ), and turns off the switch until the next switching cycle begins.

THERMAL SHUTDOWN

Thermal shutdown limits total power dissipation by turning off the output switch when the IC junction temperature exceeds 165°C. After thermal shutdown occurs, the output switch doesn't turn on until the junction temperature drops to approximately 150°C.

Design Guide

INDUCTOR SELECTION

The Duty Cycle (D) can be approximated quickly using the ratio of output voltage (V_O) to input voltage (V_{IN}):

$$D = \frac{V_{OUT}}{V_{IN}}$$

(1)

The catch diode (D1) forward voltage drop and the voltage drop across the internal PMOS must be included to calculate a more accurate duty cycle. Calculate D by using the following formula:

$$D = \frac{V_{OUT} + V_D}{V_{IN} + V_D - V_{SW}}$$

(2)

V_{SW} can be approximated by:

$$V_{SW} = I_{OUT} \times R_{DSON}$$

(3)

The diode forward drop (V_D) can range from 0.3V to 0.7V depending on the quality of the diode. The lower the V_D, the higher the operating efficiency of the converter. The inductor value determines the output ripple current. Lower inductor values decrease the size of the inductor, but increase the output ripple current. An increase in the inductor value will decrease the output ripple current.

One must ensure that the minimum current limit (2.4A) is not exceeded, so the peak current in the inductor must be calculated. The peak current (I_{LPK}) in the inductor is calculated by:

$$I_{LPK} = I_{OUT} + \Delta i_L$$

(4)
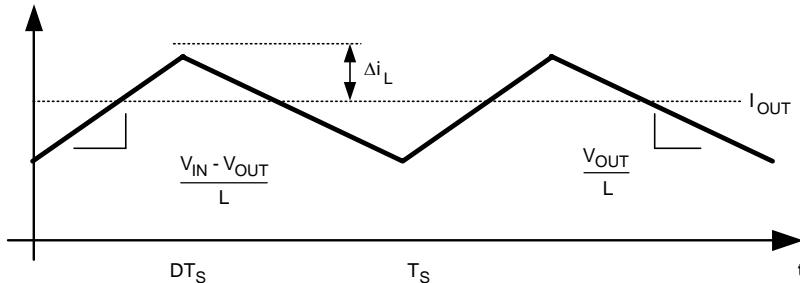
Figure 25. Inductor Current

$$\frac{V_{IN} - V_{OUT}}{L} = \frac{2\Delta i_L}{DT_S}$$

(5)

In general,

$$\Delta i_L = 0.1 \times (I_{OUT}) \rightarrow 0.2 \times (I_{OUT})$$

(6)

If Δi_L = 20% of 2A, the peak current in the inductor will be 2.4A. The minimum ensured current limit over all operating conditions is 2.4A. One can either reduce Δi_L, or make the engineering judgment that zero margin will be safe enough. The typical current limit is 3.25A.

The LM2832 operates at frequencies allowing the use of ceramic output capacitors without compromising transient response. Ceramic capacitors allow higher inductor ripple without significantly increasing output ripple. See the OUTPUT CAPACITOR for more details on calculating output voltage ripple. Now that the ripple current is determined, the inductance is calculated by:

$$L = \left(\frac{DT_S}{2\Delta i_L}\right) \times (V_{IN} - V_{OUT})$$

where

$$T_S = \frac{1}{f_S}$$

(8)   (8)

When selecting an inductor, make sure that it is capable of supporting the peak output current without saturating. Inductor saturation will result in a sudden reduction in inductance and prevent the regulator from operating correctly. Because of the speed of the internal current limit, the peak current of the inductor need only be specified for the required maximum output current. For example, if the designed maximum output current is 1.0A and the peak current is 1.25A, then the inductor should be specified with a saturation current limit of > 1.25A. There is no need to specify the saturation or peak current of the inductor at the 3.25A typical switch current limit. The difference in inductor size is a factor of 5. Because of the operating frequency of the LM2832, ferrite based inductors are preferred to minimize core losses. This presents little restriction since the variety of ferrite-based inductors is huge. Lastly, inductors with lower series resistance (R_{DCR}) will provide better operating efficiency. For recommended inductors see Example Circuits.

INPUT CAPACITOR

An input capacitor is necessary to ensure that V_{IN} does not drop excessively during switching transients. The primary specifications of the input capacitor are capacitance, voltage, RMS current rating, and ESL (Equivalent Series Inductance). The recommended input capacitance is 22 µF. The input voltage rating is specifically stated by the capacitor manufacturer. Make sure to check any recommended deratings and also verify if there is any significant change in capacitance at the operating input voltage and the operating temperature. The input capacitor maximum RMS input current rating (I_{RMS-IN}) must be greater than:

$$I_{RMS\_IN} \sqrt{D\left[I_{OUT}{}^2 (1\text{-}D) + \frac{\Delta i^2}{3}\right]}$$

(9)

Neglecting inductor ripple simplifies the above equation to:

$$I_{RMS\_IN} = I_{OUT} \times \sqrt{D(1 - D)}$$

(10)

It can be shown from the above equation that maximum RMS capacitor current occurs when D = 0.5. Always calculate the RMS at the point where the duty cycle D is closest to 0.5. The ESL of an input capacitor is usually determined by the effective cross sectional area of the current path. A large leaded capacitor will have high ESL and a 0805 ceramic chip capacitor will have very low ESL. At the operating frequencies of the LM2832, leaded capacitors may have an ESL so large that the resulting impedance ($2\pi fL$) will be higher than that required to provide stable operation. As a result, surface mount capacitors are strongly recommended.

Sanyo POSCAP, Tantalum or Niobium, Panasonic SP, and multilayer ceramic capacitors (MLCC) are all good choices for both input and output capacitors and have very low ESL. For MLCCs it is recommended to use X7R or X5R type capacitors due to their tolerance and temperature characteristics. Consult capacitor manufacturer datasheets to see how rated capacitance varies over operating conditions.

OUTPUT CAPACITOR

The output capacitor is selected based upon the desired output ripple and transient response. The initial current of a load transient is provided mainly by the output capacitor. The output ripple of the converter is:

$$\Delta V_{OUT} = \Delta I_L \left(R_{ESR} + \frac{1}{8 \times F_{SW} \times C_{OUT}}\right)$$

(11)

Product Folder Links: *LM2832*

When using MLCCs, the ESR is typically so low that the capacitive ripple may dominate. When this occurs, the output ripple will be approximately sinusoidal and 90° phase shifted from the switching action. Given the availability and quality of MLCCs and the expected output voltage of designs using the LM2832, there is really no need to review any other capacitor technologies. Another benefit of ceramic capacitors is their ability to bypass high frequency noise. A certain amount of switching edge noise will couple through parasitic capacitances in the inductor to the output. A ceramic capacitor will bypass this noise while a tantalum will not. Since the output capacitor is one of the two external components that control the stability of the regulator control loop, most applications will require a minimum of 22 µF of output capacitance. Capacitance often, but not always, can be increased significantly with little detriment to the regulator stability. Like the input capacitor, recommended multilayer ceramic capacitors are X7R or X5R types.

CATCH DIODE

The catch diode (D1) conducts during the switch off-time. A Schottky diode is recommended for its fast switching times and low forward voltage drop. The catch diode should be chosen so that its current rating is greater than:

$$I_{D1} = I_{OUT} \times (1-D) \qquad\qquad (12)$$

The reverse breakdown rating of the diode must be at least the maximum input voltage plus appropriate margin. To improve efficiency, choose a Schottky diode with a low forward voltage drop.

OUTPUT VOLTAGE

The output voltage is set using the following equation where R2 is connected between the FB pin and GND, and R1 is connected between V_O and the FB pin. A good value for R2 is 10kΩ. When designing a unity gain converter (Vo = 0.6V), R1 should be between 0Ω and 100Ω, and R2 should be equal or greater than 10kΩ.

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1 \right) \times R2 \qquad\qquad (13)$$

$$V_{REF} = 0.60V \qquad\qquad (14)$$

PCB LAYOUT CONSIDERATIONS

When planning layout there are a few things to consider when trying to achieve a clean, regulated output. The most important consideration is the close coupling of the GND connections of the input capacitor and the catch diode D1. These ground ends should be close to one another and be connected to the GND plane with at least two through-holes. Place these components as close to the IC as possible. Next in importance is the location of the GND connection of the output capacitor, which should be near the GND connections of CIN and D1. There should be a continuous ground plane on the bottom layer of a two-layer board except under the switching node island. The FB pin is a high impedance node and care should be taken to make the FB trace short to avoid noise pickup and inaccurate regulation. The feedback resistors should be placed as close as possible to the IC, with the GND of R1 placed as close as possible to the GND of the IC. The V_{OUT} trace to R2 should be routed away from the inductor and any other traces that are switching. High AC currents flow through the V_{IN}, SW and V_{OUT} traces, so they should be as short and wide as possible. However, making the traces wide increases radiated noise, so the designer must make this trade-off. Radiated noise can be decreased by choosing a shielded inductor. The remaining components should also be placed as close as possible to the IC. Please see Application Note AN-1229 SNVA054 for further considerations and the LM2832 demo board as an example of a four-layer layout.

Calculating Efficiency, and Junction Temperature

The complete LM2832 DC/DC converter efficiency can be calculated in the following manner.

$$\eta = \frac{P_{OUT}}{P_{IN}} \qquad\qquad (15)$$

Or

$$\eta = \frac{P_{OUT}}{P_{OUT} + P_{LOSS}} \qquad\qquad (16)$$

Calculations for determining the most significant power losses are shown below. Other losses totaling less than 2% are not discussed.

Product Folder Links: *LM2832*

Power loss (P_{LOSS}) is the sum of two basic types of losses in the converter: switching and conduction. Conduction losses usually dominate at higher output loads, whereas switching losses remain relatively fixed and dominate at lower output loads. The first step in determining the losses is to calculate the duty cycle (D):

$$D = \frac{V_{OUT} + V_D}{V_{IN} + V_D - V_{SW}}$$

(17)

V_{SW} is the voltage drop across the internal PFET when it is on, and is equal to:

$$V_{SW} = I_{OUT} \times R_{DSON}$$

(18)

V_D is the forward voltage drop across the Schottky catch diode. It can be obtained from the diode manufactures Electrical Characteristics section. If the voltage drop across the inductor (V_{DCR}) is accounted for, the equation becomes:

$$D = \frac{V_{OUT} + V_D + V_{DCR}}{V_{IN} + V_D + V_{DCR} - V_{SW}}$$

(19)

The conduction losses in the free-wheeling Schottky diode are calculated as follows:

$$P_{DIODE} = V_D \times I_{OUT} \times (1-D)$$

(20)

Often this is the single most significant power loss in the circuit. Care should be taken to choose a Schottky diode that has a low forward voltage drop.

Another significant external power loss is the conduction loss in the output inductor. The equation can be simplified to:

$$P_{IND} = I_{OUT}{}^2 \times R_{DCR}$$

(21)

The LM2832 conduction loss is mainly associated with the internal PFET:

$$P_{COND} = (I_{OUT}{}^2 \times D)\left(1 + \frac{1}{3} \times \left(\frac{\Delta i_L}{I_{OUT}}\right)^2\right)R_{DSON}$$

(22)

If the inductor ripple current is fairly small, the conduction losses can be simplified to:

$$P_{COND} = I_{OUT}{}^2 \times R_{DSON} \times D$$

(23)

Switching losses are also associated with the internal PFET. They occur during the switch on and off transition periods, where voltages and currents overlap resulting in power loss. The simplest means to determine this loss is to empirically measuring the rise and fall times (10% to 90%) of the switch at the switch node.

Switching Power Loss is calculated as follows:

$$P_{SWR} = 1/2(V_{IN} \times I_{OUT} \times F_{SW} \times T_{RISE})$$

(24)

$$P_{SWF} = 1/2(V_{IN} \times I_{OUT} \times F_{SW} \times T_{FALL})$$

(25)

$$P_{SW} = P_{SWR} + P_{SWF}$$

(26)

Another loss is the power required for operation of the internal circuitry:

$$P_Q = I_Q \times V_{IN}$$

(27)

I_Q is the quiescent operating current, and is typically around 2.5mA for the 0.55MHz frequency option.

Typical Application power losses are:

Table 1. Power Loss Tabulation

V_{IN}	5.0V		
V_{OUT}	3.3V	P_{OUT}	5.78W
I_{OUT}	1.75A		
V_D	0.45V	P_{DIODE}	262mW
F_{SW}	550kHz		
I_Q	2.5mA	P_Q	12.5mW
T_{RISE}	4nS	P_{SWR}	10mW
T_{FALL}	4nS	P_{SWF}	10mW
$R_{DS(ON)}$	150mΩ	P_{COND}	306mW
IND_{DCR}	50mΩ	P_{IND}	153mW
D	0.667	P_{LOSS}	753mW
η	88%	$P_{INTERNAL}$	339mW

$$\Sigma P_{COND} + P_{SW} + P_{DIODE} + P_{IND} + P_Q = P_{LOSS} \tag{28}$$

$$\Sigma P_{COND} + P_{SWF} + P_{SWR} + P_Q = P_{INTERNAL} \tag{29}$$

$$P_{INTERNAL} = 339mW \tag{30}$$

Thermal Definitions

T_J   Chip junction temperature

T_A   Ambient temperature

$R_{\theta JC}$ Thermal resistance from chip junction to device case

$R_{\theta JA}$ Thermal resistance from chip junction to ambient air

Heat in the LM2832 due to internal power dissipation is removed through conduction and/or convection.

Conduction Heat transfer occurs through cross sectional areas of material. Depending on the material, the transfer of heat can be considered to have poor to good thermal conductivity properties (insulator vs. conductor).

Heat Transfer goes as:

Silicon → package → lead frame → PCB

Convection Heat transfer is by means of airflow. This could be from a fan or natural convection. Natural convection occurs when air currents rise from the hot device to cooler air.

Thermal impedance is defined as:

$$R_\theta = \frac{\Delta T}{Power} \tag{31}$$

Thermal impedance from the silicon junction to the ambient air is defined as:

$$R_{\theta JA} = \frac{T_J - T_A}{Power} \tag{32}$$

The PCB size, weight of copper used to route traces and ground plane, and number of layers within the PCB can greatly effect $R_{\theta JA}$. The type and number of thermal vias can also make a large difference in the thermal impedance. Thermal vias are necessary in most applications. They conduct heat from the surface of the PCB to the ground plane. Four to six thermal vias should be placed under the exposed pad to the ground plane if the WSON package is used.

Thermal impedance also depends on the thermal properties of the application operating conditions (Vin, Vo, Io etc), and the surrounding circuitry.

Product Folder Links: *LM2832*

Silicon Junction Temperature Determination Method 1:

To accurately measure the silicon temperature for a given application, two methods can be used. The first method requires the user to know the thermal impedance of the silicon junction to top case temperature.

Some clarification needs to be made before we go any further.

$R_{\theta JC}$ is the thermal impedance from all six sides of an IC package to silicon junction.

$R_{\Phi JC}$ is the thermal impedance from top case to the silicon junction.

In this data sheet we will use $R_{\Phi JC}$ so that it allows the user to measure top case temperature with a small thermocouple attached to the top case.

$R_{\Phi JC}$ is approximately 30°C/Watt for the 6-pin WSON package with the exposed pad. Knowing the internal dissipation from the efficiency calculation given previously, and the case temperature, which can be empirically measured on the bench we have:

$$R_{\Phi JC} = \frac{T_J - T_C}{Power}$$

(33)

Therefore:

$$T_j = (R_{\Phi JC} \times P_{LOSS}) + T_C$$

(34)

From the previous example:

$$T_j = (R_{\Phi JC} \times P_{INTERNAL}) + T_C$$

(35)

$$T_j = 30°C/W \times 0.339W + T_C$$

(36)

The second method can give a very accurate silicon junction temperature.

The first step is to determine $R_{\theta JA}$ of the application. The LM2832 has over-temperature protection circuitry. When the silicon temperature reaches 165°C, the device stops switching. The protection circuitry has a hysteresis of about 15°C. Once the silicon temperature has decreased to approximately 150°C, the device will start to switch again. Knowing this, the $R_{\theta JA}$ for any application can be characterized during the early stages of the design one may calculate the $R_{\theta JA}$ by placing the PCB circuit into a thermal chamber. Raise the ambient temperature in the given working application until the circuit enters thermal shutdown. If the SW-pin is monitored, it will be obvious when the internal PFET stops switching, indicating a junction temperature of 165°C. Knowing the internal power dissipation from the above methods, the junction temperature, and the ambient temperature $R_{\theta JA}$ can be determined.

$$R_{\theta JA} = \frac{165° - Ta}{P_{INTERNAL}}$$

(37)

Once this is determined, the maximum ambient temperature allowed for a desired junction temperature can be found.

An example of calculating $R_{\theta JA}$ for an application using the Texas Instruments LM2832 WSON demonstration board is shown below.

The four layer PCB is constructed using FR4 with ½ oz copper traces. The copper ground plane is on the bottom layer. The ground plane is accessed by two vias. The board measures 3.0cm x 3.0cm. It was placed in an oven with no forced airflow. The ambient temperature was raised to 126°C, and at that temperature, the device went into thermal shutdown.

From the previous example:

$$P_{INTERNAL} = 339mW$$

(38)

$$R_{\theta JA} = \frac{165^oC - 126^oC}{339\ mW} = 115^o\ C/W$$

(39)

If the junction temperature was to be kept below 125°C, then the ambient temperature could not go above 86°C.

$$T_j - (R_{\theta JA} \times P_{LOSS}) = T_A$$

(40)

125°C - (115°C/W x 339mW) = 86°C (41)

WSON Package
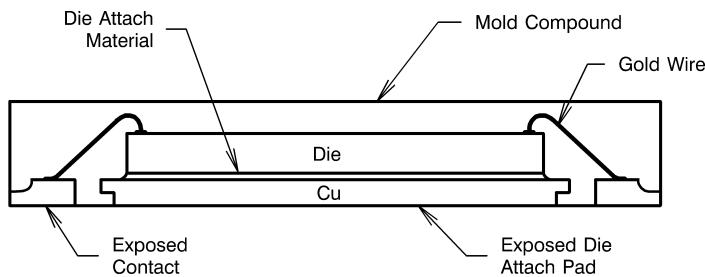
Figure 26. Internal WSON Connection

For certain high power applications, the PCB land may be modified to a "dog bone" shape (see Figure 27). By increasing the size of ground plane, and adding thermal vias, the $R_{\theta JA}$ for the application can be reduced.
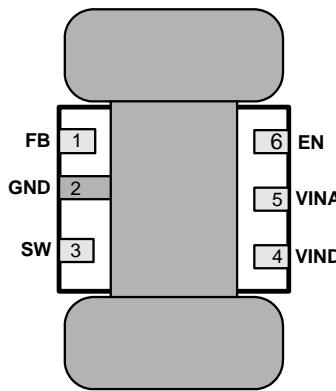
Figure 27. 6-Lead WSON PCB Dog Bone Layout

LM2832X Design Example 1
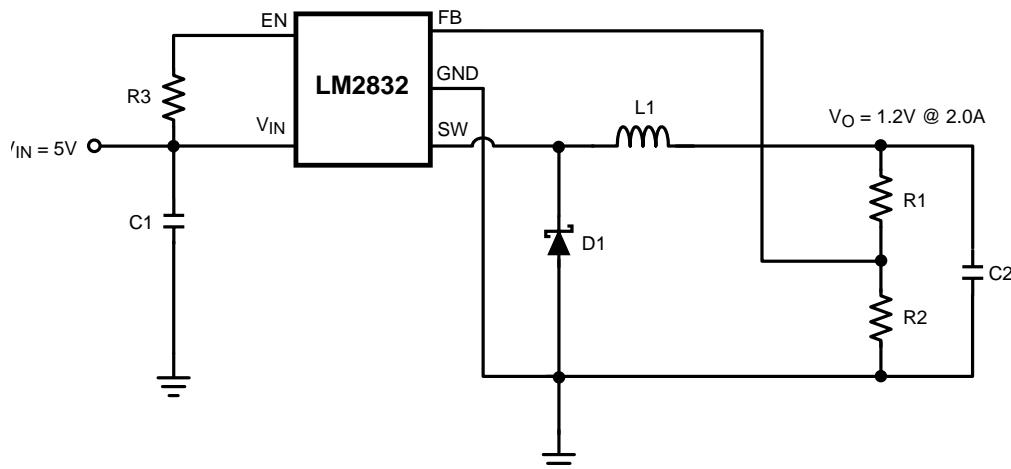
Figure 28. LM2832X (1.6MHz): Vin = 5V, Vo = 1.2V @ 2.0A

Table 2. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	2.0A Buck Regulator	TI	LM2832X
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	0.4V_f Schottky 2A, 20V_R	Diodes Inc.	B220/A
L1	2.2µH, 3.5A	Coilcraft	DS3316P-222
R2	15.0kΩ, 1%	Vishay	CRCW08051502F
R1	15.0kΩ, 1%	Vishay	CRCW08051502F
R3	100kΩ, 1%	Vishay	CRCW08051003F

LM2832X Design Example 2
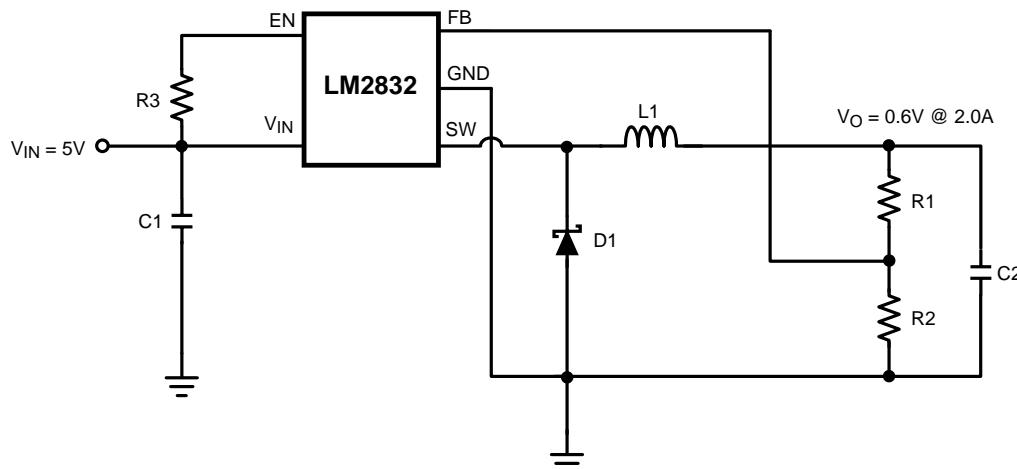
Figure 29. LM2832X (1.6MHz): Vin = 5V, Vo = 0.6V @ 2.0A

Table 3. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	2.0A Buck Regulator	TI	LM2832X
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	0.4V$_f$ Schottky 2A, 20V$_R$	Diodes Inc.	B220/A
L1	3.3µH, 3.3A	Coilcraft	DS3316P-332
R2	10.0kΩ, 1%	Vishay	CRCW08051000F
R1	0Ω		
R3	100kΩ, 1%	Vishay	CRCW08051003F

LM2832X Design Example 3
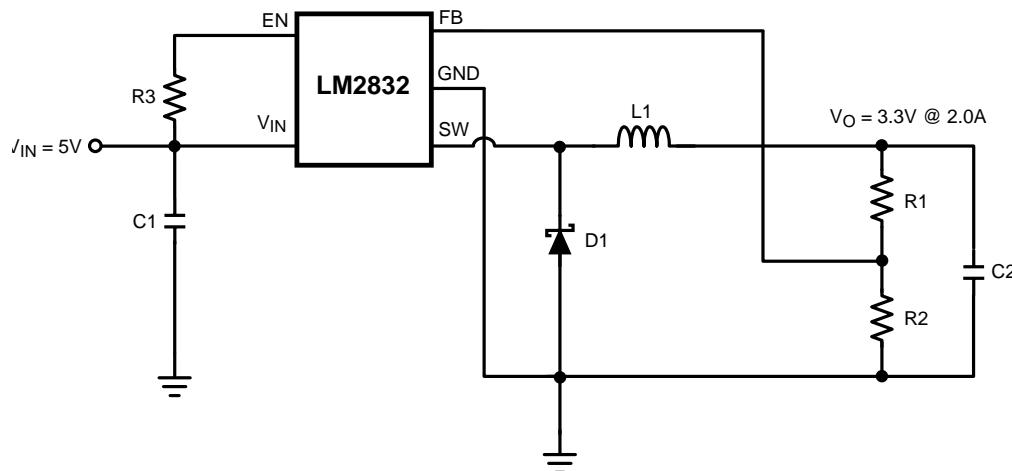
Figure 30. LM2832X (1.6MHz): Vin = 5V, Vo = 3.3V @ 2.0A

Table 4. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	2.0A Buck Regulator	TI	LM2832X
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	$0.4V_f$ Schottky 2A, $20V_R$	Diodes Inc.	B220/A
L1	2.2µH, 2.8A	Coilcraft	ME3220-222
R2	10.0kΩ, 1%	Vishay	CRCW08051002F
R1	45.3kΩ, 1%	Vishay	CRCW08054532F
R3	100kΩ, 1%	Vishay	CRCW08051003F

Product Folder Links: *LM2832*

LM2832Y Design Example 4
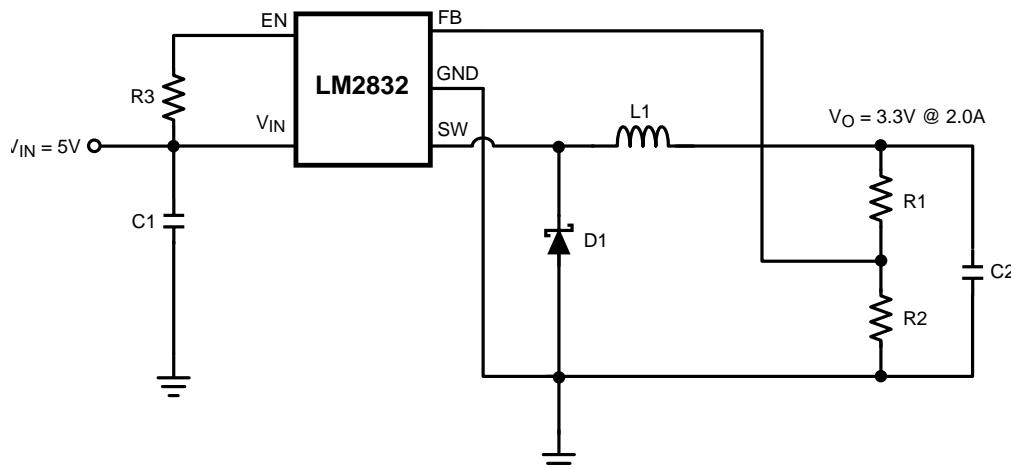
Figure 31. LM2832Y (550kHz): Vin = 5V, Vout = 3.3V @ 2.0A

Table 5. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	1.5A Buck Regulator	TI	LM2832Y
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	0.3V_f Schottky 1.5A, 30V_R	TOSHIBA	CRS08
L1	4.7µH 2.1A	TDK	SLF7045T-4R7M2R0-PF
R1	10.0kΩ, 1%	Vishay	CRCW08051002F
R2	10.0kΩ, 1%	Vishay	CRCW08051002F

LM2832Y Design Example 5
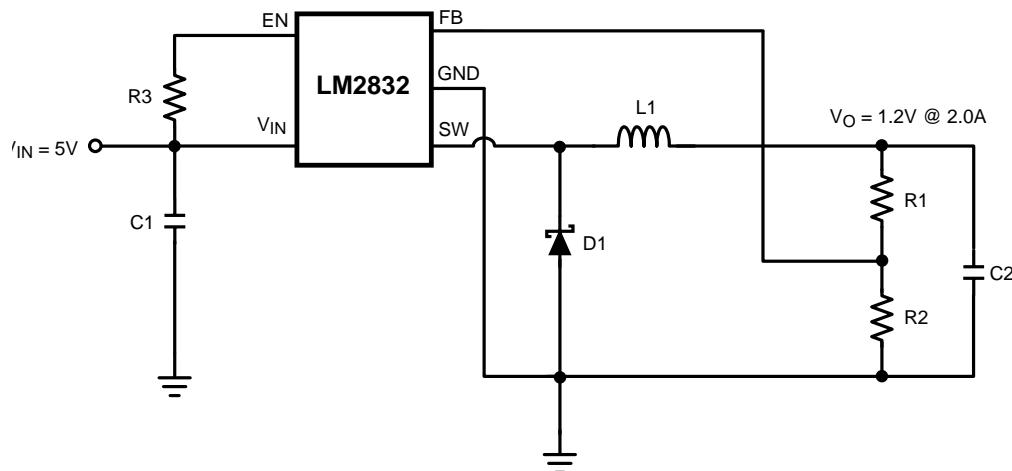
Figure 32. LM2832Y (550kHz): Vin = 5V, Vout = 1.2V @ 2.0A

Table 6. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	1.5A Buck Regulator	TI	LM2832Y
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	0.3V_f Schottky 1.5A, 30V_R	TOSHIBA	CRS08
L1	6.8µH 1.8A	TDK	SLF7045T-6R8M1R7
R1	10.0kΩ, 1%	Vishay	CRCW08051002F
R2	10.0kΩ, 1%	Vishay	CRCW08051002F

Product Folder Links: *LM2832*

LM2832Z Design Example 6

Figure 33. LM2832Z (3MHz): Vin = 5V, Vo = 3.3V @ 2.0A

Table 7. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	2.0A Buck Regulator	TI	LM2832Z
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	0.4V_f Schottky 2A, 20V_R	Diodes Inc.	B220/A
L1	3.3µH, 3.3A	Coilcraft	DS3316P-332
R2	10.0kΩ, 1%	Vishay	CRCW08051002F
R1	45.3kΩ, 1%	Vishay	CRCW08054532F
R3	100kΩ, 1%	Vishay	CRCW08051003F

LM2832Z Design Example 7
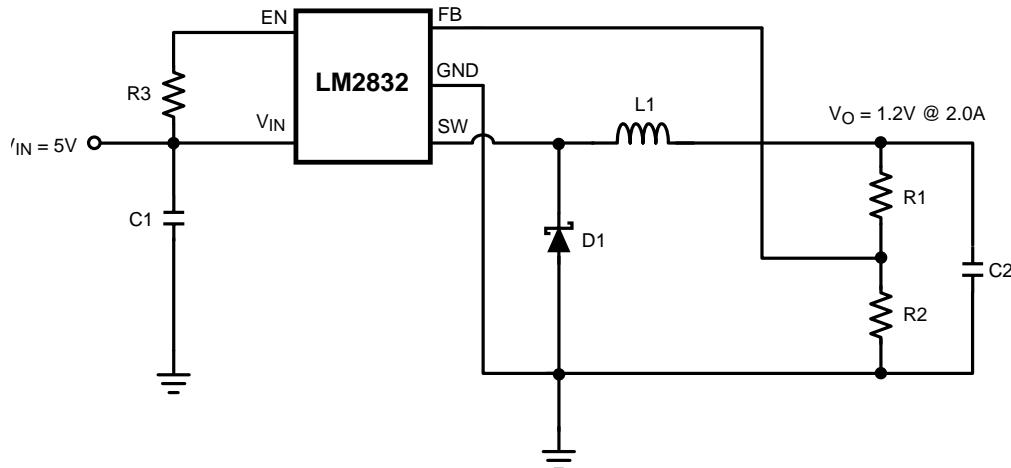
Figure 34. LM2832Z (3MHz): Vin = 5V, Vo = 1.2V @ 2.0A

Table 8. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	2.0A Buck Regulator	TI	LM2832Z
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
D1, Catch Diode	0.4V_f Schottky 2A, 20V_R	Diodes Inc.	B220/A
L1	4.7µH, 2.7A	Coilcraft	DS3316P-472
R2	10.0kΩ, 1%	Vishay	CRCW08051002F
R1	10.0kΩ, 1%	Vishay	CRCW08051002F
R3	100kΩ, 1%	Vishay	CRCW08051003F

LM2832X Dual Converters with Delayed Enabled Design Example 8
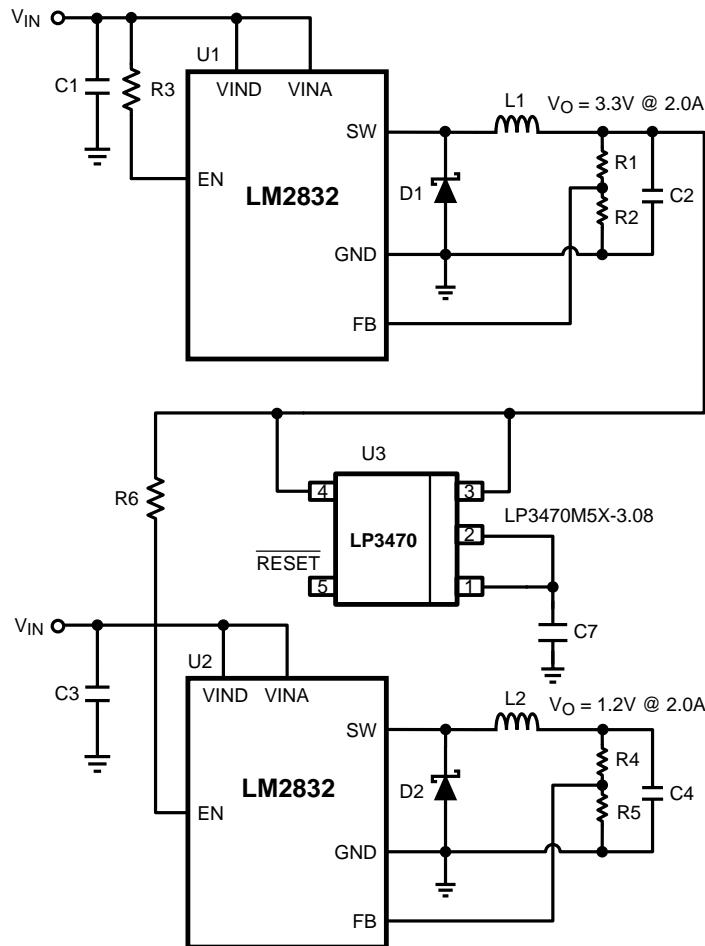
Figure 35. LM2832X (1.6MHz): Vin = 5V, Vo = 1.2V @ 2.0A & 3.3V @2.0A

Table 9. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1, U2	2.0A Buck Regulator	TI	LM2832X
U3	Power on Reset	TI	LP3470M5X-3.08
C1, C3 Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, C4 Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C7	Trr delay capacitor	TDK	
D1, D2 Catch Diode	0.4V_f Schottky 2A, 20V_R	Diodes Inc.	B220/A
L1, L2	3.3µH, 2.7A	Coilcraft	ME3220-102
R2, R4, R5	10.0kΩ, 1%	Vishay	CRCW08051002F
R1, R6	45.3kΩ, 1%	Vishay	CRCW08054532F
R3	100kΩ, 1%	Vishay	CRCW08051003F

LM2832X Buck Converter & Voltage Double Circuit with LDO Follower Design Example 9
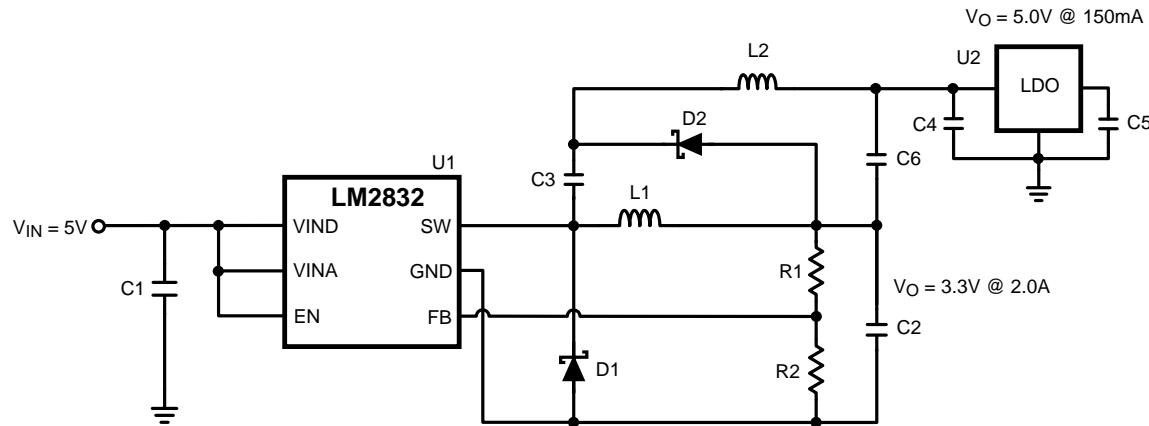
Figure 36. LM2832X (1.6MHz): Vin = 5V, Vo = 3.3V @ 2.0A & LP2986-5.0 @ 150mA

Table 10. Bill of Materials

Part ID	Part Value	Manufacturer	Part Number
U1	2.0A Buck Regulator	TI	LM2832X
U2	200mA LDO	TI	LP2986-5.0
C1, Input Cap	22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C2, Output Cap	2x22µF, 6.3V, X5R	TDK	C3216X5ROJ226M
C3 – C6	2.2µF, 6.3V, X5R	TDK	C1608X5R0J225M
D1, Catch Diode	0.4V_f Schottky 2A, 20V_R	Diodes Inc.	B220/A
D2	0.4V_f Schottky 20V_R, 500mA	ON Semi	MBR0520
L2	10µH, 800mA	CoilCraft	ME3220-103
L1	2.2µH, 3.5A	CoilCraft	DS3316P-222
R2	45.3kΩ, 1%	Vishay	CRCW08054532F
R1	10.0kΩ, 1%	Vishay	CRCW08051002F

REVISION HISTORY

Changes from Original (April 2013) to Revision A   **Page**

PACKAGING INFORMATION

Orderable part number (1)	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2832XMY/NOPB	Active	Production	HVSSOP (DGN) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLBB
LM2832XMY/NOPB.A	Active	Production	HVSSOP (DGN) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLBB
LM2832XSD/NOPB	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L196B
LM2832XSD/NOPB.A	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L196B
LM2832XSD/NOPB.B	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	-	SN	Level-3-260C-168 HR	-40 to 125	L196B
LM2832YMY/NOPB	Active	Production	HVSSOP (DGN) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLCB
LM2832YMY/NOPB.A	Active	Production	HVSSOP (DGN) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLCB
LM2832YSD/NOPB	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L197B
LM2832YSD/NOPB.A	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L197B
LM2832YSD/NOPB.B	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	-	SN	Level-3-260C-168 HR	-40 to 125	L197B
LM2832ZMY/NOPB	Active	Production	HVSSOP (DGN) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLDB
LM2832ZMY/NOPB.A	Active	Production	HVSSOP (DGN) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SLDB
LM2832ZSD/NOPB	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L198B
LM2832ZSD/NOPB.A	Active	Production	WSON (NGG) | 6	1000 | SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L198B

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS
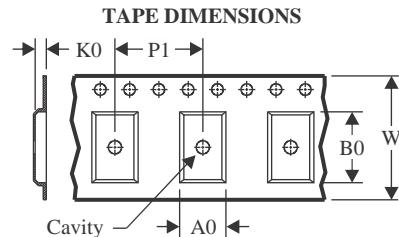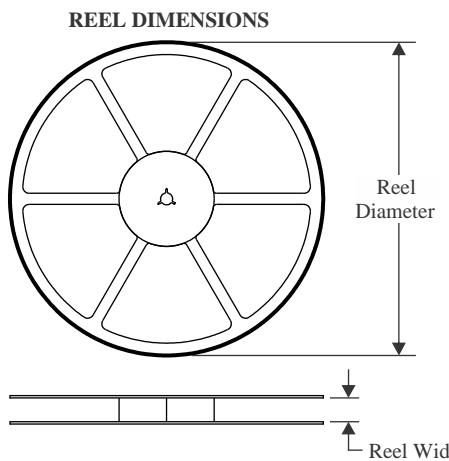
TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
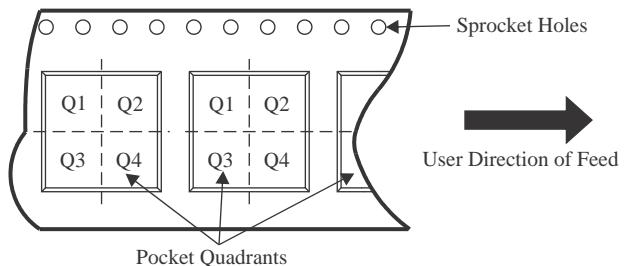
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2832XMY/NOPB	HVSSOP	DGN	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2832XSD/NOPB	WSON	NGG	6	1000	177.8	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM2832YMY/NOPB	HVSSOP	DGN	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2832YSD/NOPB	WSON	NGG	6	1000	177.8	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM2832ZMY/NOPB	HVSSOP	DGN	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2832ZSD/NOPB	WSON	NGG	6	1000	177.8	12.4	3.3	3.3	1.0	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS
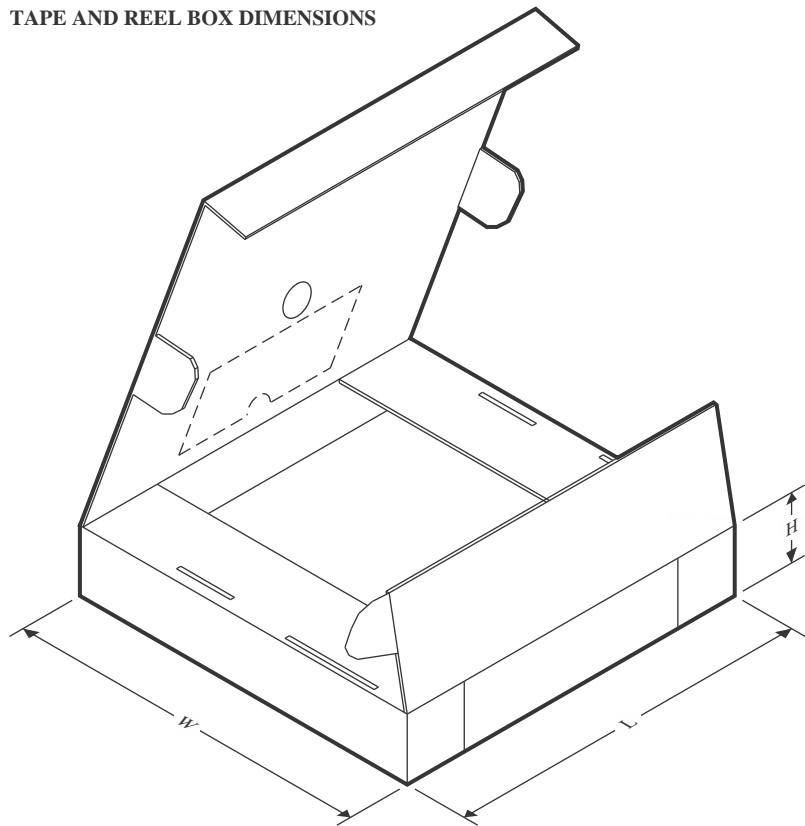
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2832XMY/NOPB	HVSSOP	DGN	8	1000	210.0	185.0	35.0
LM2832XSD/NOPB	WSON	NGG	6	1000	208.0	191.0	35.0
LM2832YMY/NOPB	HVSSOP	DGN	8	1000	210.0	185.0	35.0
LM2832YSD/NOPB	WSON	NGG	6	1000	208.0	191.0	35.0
LM2832ZMY/NOPB	HVSSOP	DGN	8	1000	210.0	185.0	35.0
LM2832ZSD/NOPB	WSON	NGG	6	1000	208.0	191.0	35.0

A

5.05
4.75 TYP

PIN 1 INDEX AREA

1

8

6X 0.65

2X
1.95

3.1
2.9
NOTE 3

4

5

8X 0.38
0.25

⊕ 0.13 Ⓜ C A B

B

3.1
2.9
NOTE 4

C

◯ 0.1 C

SEATING
PLANE

0.23
0.13

SEE DETAIL A

EXPOSED THERMAL PAD

4

5

2.0
1.7

9

8

1

1.88
1.58

0.25
GAGE PLANE

0°-8°

0.7
0.4

1.1 MAX

0.15
0.05

DETAIL A
TYPICAL
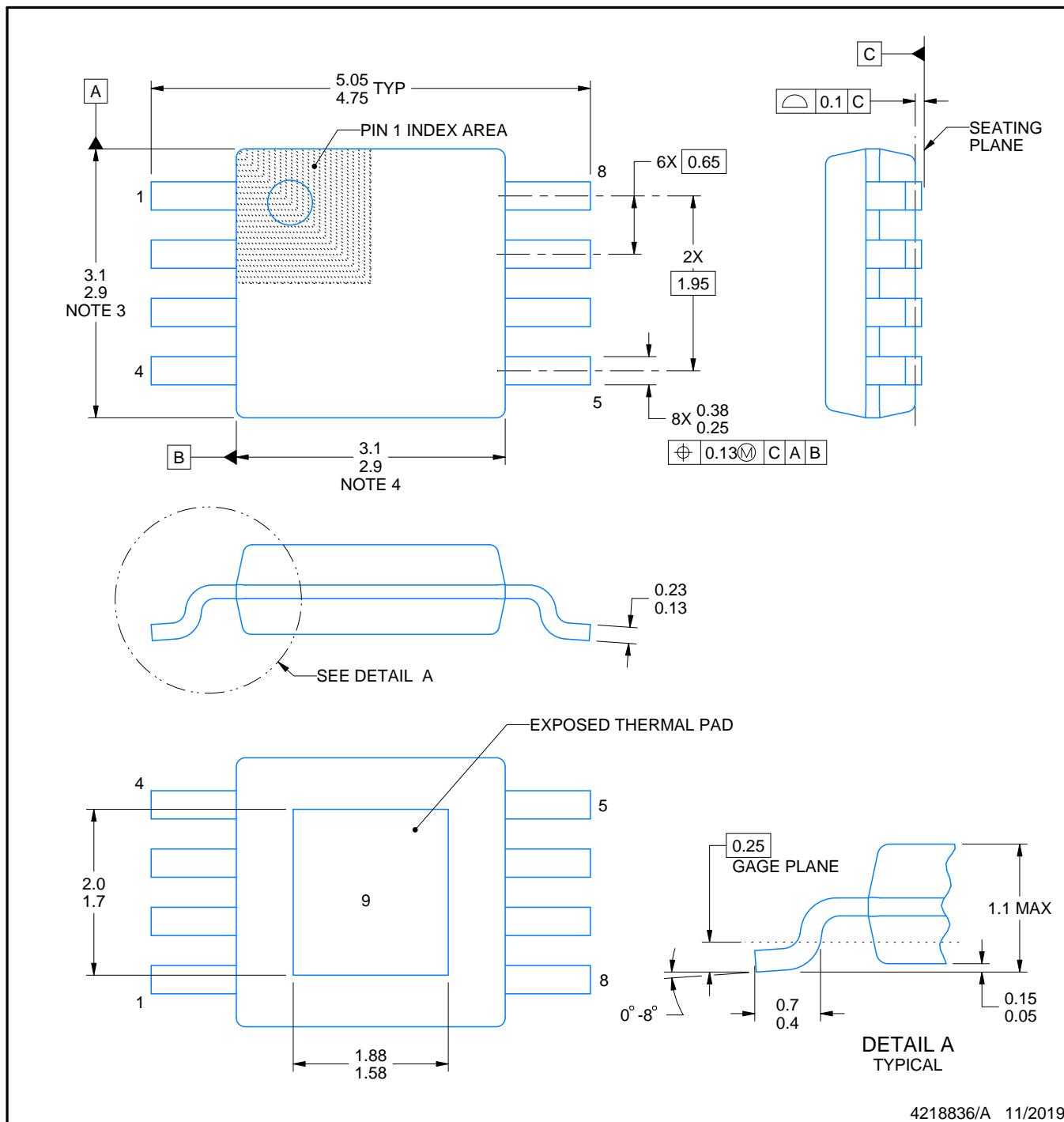
4218836/A   11/2019

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

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METAL COVERED
BY SOLDER MASK

SOLDER MASK
DEFINED PAD

(2)
NOTE 9

(1.88)

SYMM

(R0.05) TYP

8X (1.4)

8X (0.45)   1

8

(3)
NOTE 9

9

SYMM

(2)

6X (0.65)

(1.22)

4

5

(⌀ 0.2) TYP
VIA

SEE DETAILS

(0.55)

(4.4)
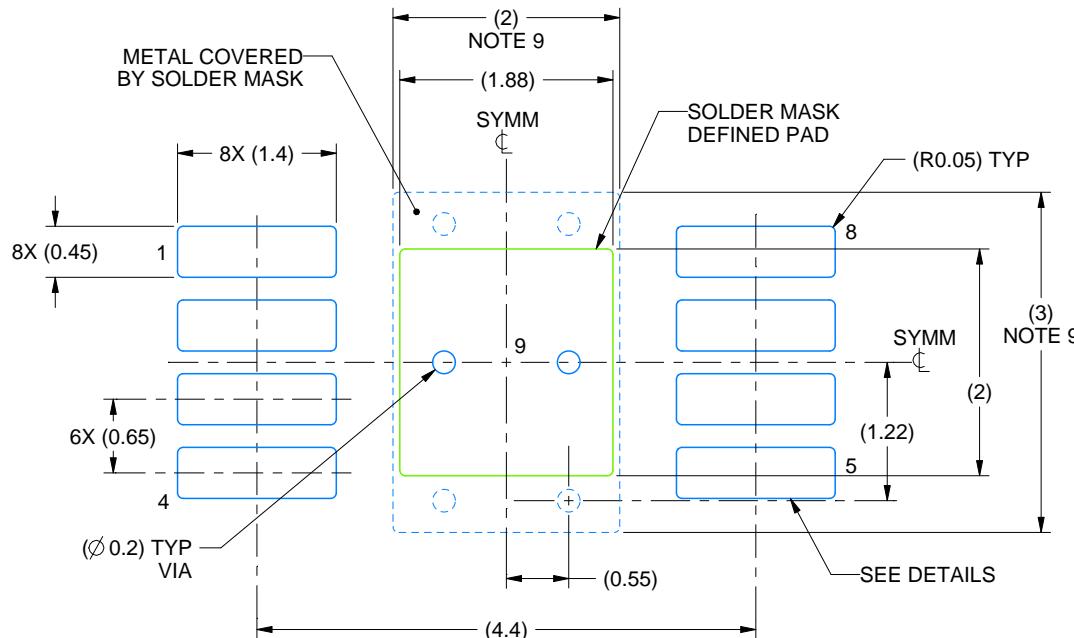
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK DETAILS

SOLDER MASK
DEFINED
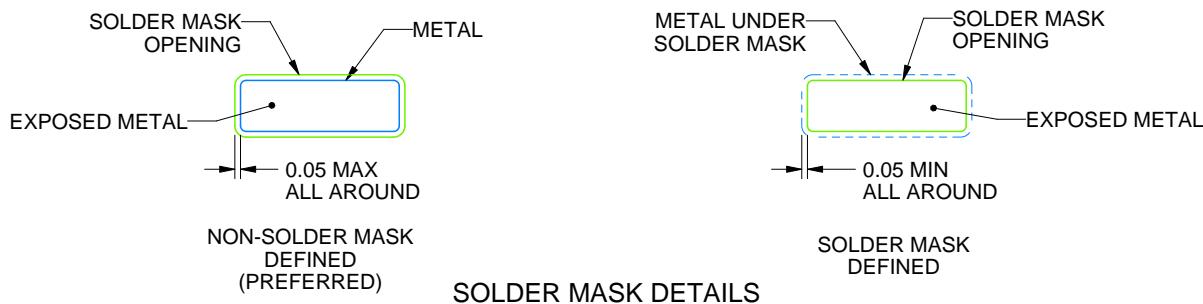
4218836/A   11/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
   on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

DGN0008A

SMALL OUTLINE PACKAGE

(1.88)
BASED ON
0.125 THICK
STENCIL

SYMM
₵

8X (1.4)

8X (0.45)   1

(R0.05) TYP

8

SYMM
₵

(2)
BASED ON
0.125 THICK
STENCIL

6X (0.65)

4

5

METAL COVERED
BY SOLDER MASK

(4.4)

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES
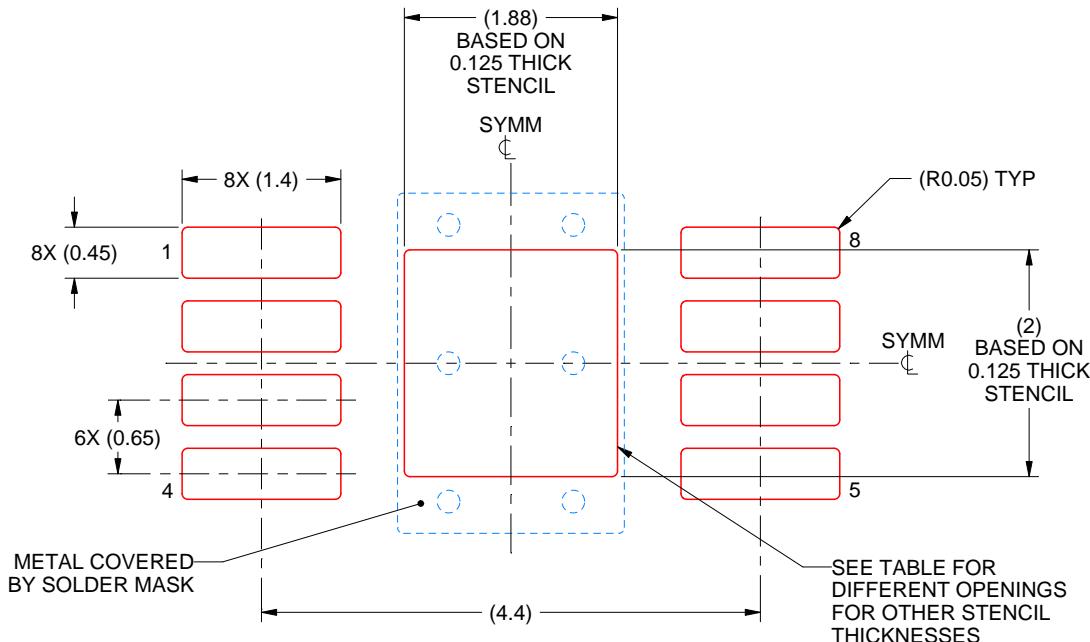
SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

| STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	2.10 X 2.24
0.125	1.88 X 2.00 (SHOWN)
0.15	1.72 X 1.83
0.175	1.59 X 1.69

4218836/A   11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

NGG0006A

(2.1)

(1.6)   (2.8)

(6X 0.6)

(6X 0.35)

(4X 0.95)

RECOMMENDED LAND PATTERN

DIMENSIONS ARE IN MILLIMETERS
DIMENSION IN ( ) FOR REFERENCE ONLY

(0.1)

PIN 1 INDEX AREA

3±0.1

B

3±0.1   A

0.8 MAX

C

PIN 1 ID

(45° X 0.25)

2.1±0.1

1   3

1.6±0.1

6X 0.4±0.1

6   4

6X 0.35±0.05

⊕ | 0.1Ⓜ | C | AⓈ | BⓈ

2X | 1.9

4X | 0.95

SDE06A (Rev A)
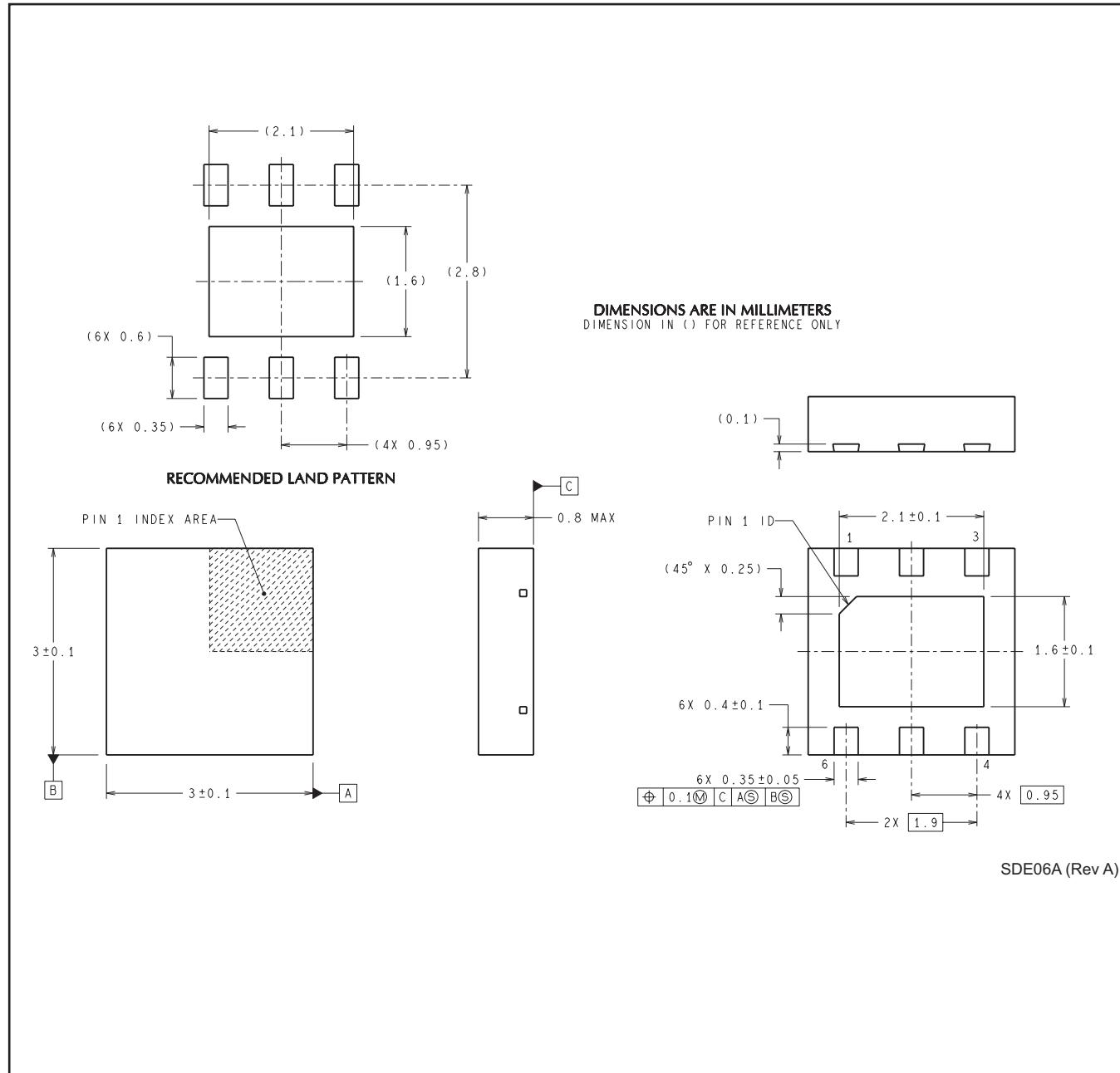
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